# Redox-dependent Franck-Condon blockade and avalanche transport in a graphene-fullerene single-molecule transistor

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### Abstract

We report transport measurements on a 26 2 graphene-fullerene single-molecule tran-27 sistor. The robust architecture where a functionalised  $C_{60}$  binds to graphene na-5 noelectrodes results in strong electron-6 vibron coupling and weak vibron re-7 Using a combined approach laxation. 8 of transport spectroscopy, Raman spec-9 troscopy and DFT calculations, we 10 demonstrate center-of-mass oscillations, 35 11 redox-dependent Franck-Condon block-12 ade and a transport regime character-13 ized by avalanche tunnelling in a single-14 molecule transistor. 15

Coupling between electronic and vibrational 16 degrees of freedom in single-molecule devices 17 can lead to transport properties very different 18 from those of metal/semiconductor nanostruc-19 tures.<sup>1</sup> Charge transfer can excite vibrational 20 modes,<sup>2</sup> or vibrons, and strong electron-vibron 21 coupling leads to suppression of tunnel current 22 at low bias.<sup>3,4</sup> Theory further predicts super-23

Poissonian current noise, characterised by giant Fano factors, for molecular junctions with weak vibron-relaxation owing to avalanche-type charge transfer.<sup>5</sup> Here, we demonstrate a robust architecture of a single-molecule transistor where a functionalised  $C_{60}$  binds to graphene nano-electrodes via  $\pi - \pi$  interactions. The stability and weak vibron-relaxation of our system enables us to investigate redox-dependent electron-vibron coupling and avalanche transport.

We perform transport measurements of graphene-fullerene single-molecule transisfabricated using feedback-controlled tors electroburning.<sup>6</sup> The molecule bridging the graphene nano-gap is a pyrene functionalised  $C_{60}$  bisadduct synthesised through a 1,3 dipolar cycloaddition using 1-pyrene carboxaldehyde and N-methylglycine (Supplementary section 1.1).<sup>7</sup> While the functionalisation results in different isomers, steric considerations mean only the cis-2 and cis-3 isomers are expected to bridge the graphene nano-gap. Density Functional Theory (DFT) calculations of the relaxed graphene-fullerene-graphene structure confirm that the cis-3 isomer forms the most stable configuration without steric hindrance, as shown in Figure 1a. Iso-surfaces of the frontier orbitals of gas phase cis-3 isomer are shown in Figure

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1b.<sup>8</sup> The wavefunction of the lowest unoccupied 53 molecular orbital (LUMO) level is mostly local-54 ized in the central  $C_{60}$ , whereas for the highest 55 occupied molecular orbital (HOMO) level, the 56 wavefunction is extended to the pyrene an-57 chors. Comparison of the iso-surfaces of fron-58 tier orbitals for cis-2 and cis-3 isomers further 59 show that the wavefunction delocalization of 60 the HOMO levels are more pronounced in the 61 cis-3 isomer, indicating that it has a better 62  $\pi$ - $\pi$  interaction with the graphene electrodes 63 and is therefore more likely to bridge the junc-64 tion (Supplementary Figure S11). In pristine 65  $C_{60}$ , DFT predicts LUMO dominated transport 66 which was verified with thermoelectric experi-67 ments.<sup>9</sup> In contrast, our DFT calculations pre-68 dict that charge transport in the bisadduct is 69 more likely to be HOMO dominated.<sup>10,11</sup> 70

Figure 1c shows the current I as a function 71 of bias  $V_b$  and gate  $V_g$  voltage of a single-72 molecule transistor (device A), measured at 73 20 mK. The addition energies between adja-74 cent redox states, measured from the height 75 of the Coulomb diamonds, are  $E_{\rm add} \sim 160$ 76 meV for all charge-state transitions. We at-77 tribute the absence of odd/even oscillations of 78  $E_{\rm add}$ , previously observed for two-fold spin shell 79 systems,  $^{6,12}$  to orbital degeneracies of the C<sub>60</sub> 80 molecule.<sup>13</sup> Calculations have shown that the 81 interactions within each shell in  $C_{60}$  are al-82 most constant, with only a slight increase of 83 the electron-electron on-site Coulomb interac-84 tion in the middle of each shell where electrons 85 with opposite spins begin to fill.<sup>13</sup> We observe a 86 small increase of  $\sim 10 \text{ meV}$  per electron added 87 from charge state N to N + 2 which we at-88 tribute to the on-site Coulomb interactions. In 89 the constant interaction model  $E_{add}$  is given 90 by the sum of the charging energy  $E_C$ , due 91 to Coulomb interactions of the electrons in the 92 molecule, and the energy gap  $\Delta_{\rm HL}$  between the 93 HOMO and LUMO.<sup>14</sup> For a two-fold degen-94 erate system,  $E_{\text{add}}$  oscillates between  $E_C$  and 95  $E_C + \Delta_{\rm HL}$ , while for systems with higher degen-96 eracies,  $E_{\text{add}} = E_C$  until a level is completely 97 filled. From the fact that  $E_{\text{add}}$  here is constant 98 for three charge-state transitions, we infer that 99 electrons are filling exclusively a HOMO that is 100 at least four-fold degenerate. This is consistent 101

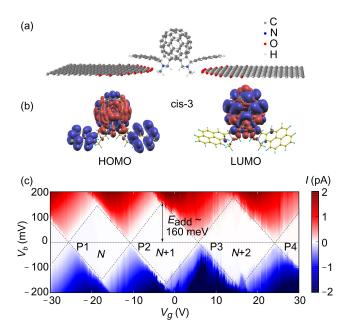


Figure 1: (a) DFT calculations showing the relaxed structure of the cis-3 isomer bridging the graphene nano-gap. The electrodes are fabricated using feedback-controlled electroburning of chemical vapour deposition grown graphene transferred to a heavily doped silicon substrate with a 300 nm thick silicon oxide layer, which also serves as a back-gate that electrostatically modulates the chemical potential of the molecule. The molecules are deposited on the electrodes from a chloroform solution (Methods). (b) DFT simulations of the iso-surfaces of the LUMO and HOMO of cis-3 isomer. (c) Current stability diagram of device A. All measurements are performed at 20 mK unless otherwise stated. Within each diamond, the system is in Coulomb blockade (CB) and the charge on the molecule is stable. The molecular redox state changes by one between adjacent diamonds.

with our DFT prediction of HOMO dominated 125 transport and calculations of the Kohn-Sham 126 HOMO and LUMO energies, which show that 127 the HOMO (-4.59 eV) and HOMO-1 (-4.60 eV) 128 levels are almost degenerate in energy, in con- 129 trast to the LUMO (-3.12 eV) and LUMO+1 130 (-2.86 eV) levels (Supplementary section 2.3). 131

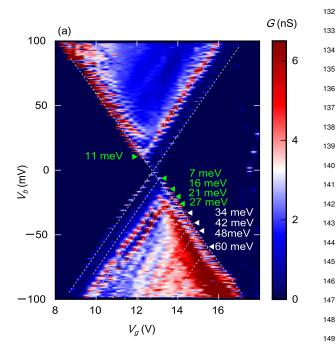


Figure 2: (a) Conductance stability diagram of <sup>150</sup> the N + 1 to N + 2 transition (P3 in Figure 1c) <sup>151</sup> obtained by taking the numerical derivative of <sup>152</sup> the current measured. Excited states are indi- <sup>153</sup> cated by the white and green arrows. Details <sup>154</sup> on how the excited states are determined are <sup>155</sup> included in Supplementary section 1.5. <sup>156</sup>

Figure 2 shows a map of the differential con-<sup>158</sup> 109 ductance G of charge transition N+1 to N+2 <sup>159</sup> 110 of device A taken with a higher resolution <sup>160</sup> 111 (P3 in Figure 1c). The gate potential for the 112 charge transition is different for repeated mea-113 surements due to a common hysteretic effect 114 likely related to charge traps in the oxide. The 115 effect occurs when the gate potential is swept 116 quickly across a large range, but is otherwise 117 stable when swept slowly. We observe lines cor-118 responding to excited state transitions at ener-119 gies > 33 meV (white arrows) that are in ex-120 cellent agreement with the intrinsic vibrational 121 modes of pristine  $C_{60}$ ,<sup>15</sup> as summarized in Ta-122 ble 1. We also observe excited states at energies 123 < 33 meV (green arrows), below the lowest vi-124

brational mode of the pristine  $C_{60}$ . The asymmetry of the excited states on the bias polarity can be explained through a rate equation model involving asymmetric tunnelling barriers, which was previously observed in the orbital excited state spectrum of a single donor in silicon. When the excited state relaxations are fast compared to the tunneling rates, an electron can tunnel on to the molecule through any number of excited states that lie within the bias window but only leave through the ground state as the molecule relaxes. In the limit where the molecule-electrodes coupling is very asymmetric, current steps are not expected for one bias polarity.<sup>16</sup>

A comparison of the transport spectroscopy and Raman spectra of pristine  $C_{60}$  and bisadduct (Table 1) indicates that these excited state transitions have a vibrational nature. To identify the mechanical motion of these additional low-lying vibrational modes, we use DFT results where we analyse the mechanical degrees of freedom of the bisadduct in the limit where the atomic mass of the pyrene anchor groups approach infinity (Supplementary section 2.6). In this limit, the anchor groups are effectively clamped and the modes corresponding to internal vibrations of the pyrene are filtered from the vibrational spectrum. DFT calculations in this limit reveal six vibrational modes at energies < 33 meV, with two sets of three modes each corresponding to the translational and rotational center-of-mass motion of the central  $C_{60}$ with respect to the anchor groups (Supplementary Figure S13a, animations in Supplementary Information).

Mc	ode	Energy (meV)			
		Transport	Raman	DFT	C <sub>60</sub>
		(this work)	(this work)	(this work)	$(Ref.^{15})$
CM	$T_y$	7		8	
CM	$T_x$			10	
CM	$R_z$	11	13	12	
CM	$T_z$	16	16	16	
CM	$R_x$	21	19	19	
CM	$R_y$	27	25	21	
$H_{g}$	(1)	34	33	32, 33, 34	33
$T_{2u}$	(1)	42			43
$G_u$	(1)	42			43
$H_{g}$	(2)	48	55		53
$A_g$	(1)	60	61		61

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Table 1: Comparison between measured excitation energies from transport and Raman spectroscopy, calculated values and intrinsic vibrational modes of pristine  $C_{60}$ . Transport measurements are performed at 20 mK in vacuum with the molecule anchored to graphene electrodes. Raman spectroscopy is performed at room temperature with the molecules dropcasted on to gold coated silicon substrates to enhance the Raman scattering. DFT calculations are performed with the condition where the degrees of motion of the anchor groups are completely restricted in order to elucidate the center-of-mass motions. In the actual system, the pyrene groups are expected to exhibit small motions. The values for the vibrational modes of pristine  $C_{60}$  are obtained from.<sup>15</sup> We find that the discrepancies between our measurements fall within the range of values reported in ref. 18, which are obtained from experiments and *ab initio* theories reported by different groups and can differ by up to 10 meV.

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Figure 3 shows low energy excitations ob-163 served for all four charge transitions (P1-4 in 164 Figure 1c) with spacings of 1.7 meV (P1), 1.5 165 meV (P2) 1.7 meV (P3) and 1.5 meV (P4)166 (white arrows). Low energy excitations are sim-167 ilarly observed in measurements of device B 168  $(\sim 2 \text{ meV}, \text{ Supplementary Figure S7a})$ . Lines 169 with different slopes, corresponding to different 170 capacitive couplings, are probably not related 171 to the energy spectrum of the molecule. They 172 can be from a different Coulomb diamond re-173 lated to a separate quantum dot located close 174 to the device or associated with density of states 175 fluctuations in the graphene electrodes. Simi-176 lar fluctuations have also been observed in sil-177 icon SETs.<sup>17</sup> To account for the nature of the 178 low energy excitations ( $\sim 2 \text{ meV}$ ), we analyse 179 the vibrational modes of the bisadduct using 180 DFT where all the mechanical degrees of free-181 dom of the atoms are allowed (Supplementary 182 section 2.6). The lowest non-zero mode is at 1.7183 meV, consistent with our measurements (Sup-184 plementary Figure S13b). This mode is due 185 to the combined center-of-mass motions of the 186 central  $C_{60}$  and pyrene anchors moving perpen-187 dicularly relative to each other, with the central 188

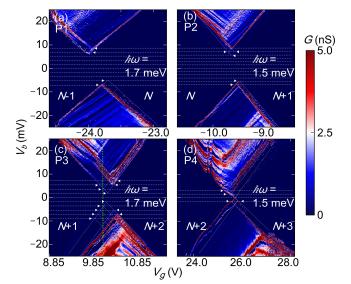


Figure 3: (a-d) Conductance stability diagrams for transitions N-1 to N+3. The low bias current suppression is due to FC blockade in systems with strong electron-vibron coupling. Sets of integer spaced vibrational state lines (white arrows) are observed in the low bias regime. The vertical green line in (c) is the gate voltage at which the large current noise discussed in Figure 5 is measured. The energy of a single vibrational quantum,  $\hbar\omega$ , is extracted for all 4 charge transitions (Supplementary section 1.5). These energy spacings are determined by first fitting the peaks of the excited state transitions at two different  $V_q$  to a thermally broadened Lorentzian in order to extract the peak position and slopes.  $\hbar\omega$  is then determined by the intersection of the excited state lines with the Coulomb diamond edges.

 $C_{60}$  moving out-of-plane while the anchors move 238 189 in-plane (animation in Supplementary Informa- 239 190 tion). Our findings are consistent with a pre- 240 191 vious report that the binding energy of pyrene 241 192 to graphene is much stronger out-of-plane com- 242 193 pared to in-plane, such that the pyrene an- 243 194 chors can more easily slide on the graphene elec- 244 195 trodes.<sup>18</sup> 245 196

The Coulomb diamond edges do not intersect 246 197 at zero bias for P1 to 3 (Figure 3a-c) and in de- 247 198 vice C (Supplementary Figure S7b). The cur- 248 199 rent suppression at low bias remain unchanged 249 200 with the application of a magnetic field, ruling 250 201 out a magnetic origin (Supplementary Figure 251 202  $S6)^{19}$  and the size of the gaps correspond to an 252 203 integer spacing of the energy excitations. We 253 204 attribute these features to Franck-Condon (FC) 254 205 blockade that occurs for strong electron-vibron 255 206 coupling,<sup>5</sup> illustrated in Figure 5a. Electrons 256 207 tunnelling onto the molecule shifts the equi- 257 208 librium coordinates of the harmonic oscillator 258 209 wavefunctions for charge states N and N + 1 <sup>259</sup> 210 by an amount proportional to the dimension- 260 211 less electron-vibron coupling constant  $\lambda$ . For 261 212 strong coupling,  $\lambda \gg 1$ , the equilibrium coordi- 262 213 nates of the N + 1 charge state is greatly dis- 263 214 placed from that of the N charge state (Figure  $_{264}$ 215 5a). As a result, the transition rate between 265 216 the vibronic ground states of charge states  $N_{266}$ 217 and N+1, determined by the overlap of the 267 218 vibron wavefunctions, is exponentially reduced 268 219 with  $\lambda$ , leading to current suppression at low 269 220 bias. The FC blockade is lifted when the ap- 270 221 plied bias is sufficiently large for transitions 271 222 from the vibronic ground state to higher ex- 272 223 cited states (Figure 5c), where the transition 273 224 rates are higher from increased overlap of the 274 225 vibronic wavefunctions. When electrons are 275 226 added to the molecule, we observe a decrease 276 227 of the FC gap from P2 to P4, such that for 277 228 P4 (Figure 3d), the FC blockade is completely 278 229 lifted. The FC gap, i.e. the threshold voltage at 279 230 which the FC blockade is lifted when it matches 280 231 a multiple of the vibrational quantum  $n\hbar\omega$ , is 281 232 proportional to  $\lambda^2 \hbar \omega$ .<sup>5</sup> Additional electrons on 282 233 the molecule shift the equilibrium positions of 283 234 the harmonic oscillator wavefunctions, leading 284 235 to a smaller displacement of the equilibrium co- 285 236 ordinates between charge states N+2 and N+3, 286 237

previously FC blockade region. Redox dependent electron-vibron coupling is possibly due to Jahn-Teller (JT) distortion of the molecule,<sup>20</sup> which is particularly strong in molecules with a large orbital degeneracy and high spatial symmetry such as  $C_{60}$ .<sup>21</sup> The geometrical JT distortion lowers the overall ground state energy which is directly proportional to  $\lambda$ , as derived in ref. 23. Our observation of HOMO degeneracy and a charge state dependent  $\lambda$  is therefore in line with these predictions. Using the set of evenly spaced excitations of P3 (Figure 3c) and fitting them to the rate equation model,<sup>22</sup> we determine  $\lambda = 3.0$  for the charge transition N + 1 to N + 2 (Supplementary section 1.5). We simulate the stability

i.e. a smaller  $\lambda$ . The higher transition rate for

the vibronic ground states from the increased

wavefunction overlap allows for current in the

equation model,<sup>22</sup> we determine  $\lambda = 3.0$  for the charge transition N + 1 to N + 2 (Supplementary section 1.5). We simulate the stability diagram for an asymmetric molecule-electrode tunnel coupling, dependent on the contact geometry of the molecule to the electrodes,  $t_L =$  $0.2t_R$  (Figure 4b), which shows good qualitative agreement with our measurements (Figure 4a). The electroburnt graphene nano-electrodes are not likely to be symmetric on the atomic scale which can lead to asymmetric positioning of the molecule across the junction. Furthermore, our DFT calculations show that the pyrene anchors are not symmetric relative to the central C<sub>60</sub> (Supplementary section 2.2).

At elevated temperatures T, the thermal equilibrium population of vibrational excited states. with exponentially greater transition rates, are increased, <sup>3,4</sup> and transitions at low bias can now proceed via these states. In device A the FC gap is lifted at 3 K (Figure 4c,d), and device C at 4 K (Supplementary Figure S7b,c). We extract and fit the temperature dependence of  $I \propto 1/k_BT \times 1/(exp(\hbar\omega/k_BT)-1)^{3,4}$  at  $V_g=7$ V and  $V_b = 7.2$  mV in Figure 4c and obtained a value of  $\hbar \omega = 1.7$  meV (Supplementary Figure S8), accordant with the value measured in Figure 3c. The increase of peak intensity with temperature is in direct contrast with the case for which a Fermi-Dirac distribution is relevant, where a decrease is expected,  $I \propto 1/k_B T^{3}$ . These observation confirms the bosonic nature of the transition and is consistent with our in<sup>287</sup> terpretation of the FC model.

Low energy excitations (3 to 7 meV) were 288 previously observed for a pristine  $C_{60}$  single-289 molecule transistor connected to gold elec-290 trodes.<sup>2</sup> Those excitations were attributed to 291 nanomechanical oscillations arising from the 292 center-of-mass motion of the  $C_{60}$  and no FC 293 blockade was observed. This is due to the dif-294 ferent coupling mechanisms for internal molec-295 ular vibrations and center-of-mass oscillations. 296 While vibrations couple directly to the electron, 297 oscillations instead couple through displace-298 ment dependent tunneling matrix elements.<sup>22</sup> 299 At energies below 10 meV, it has been shown 300 that the coupling strength for oscillations is in-301 sufficient to induce FC blockade.<sup>4</sup> The observa-302 tion of FC blockade from the 1.7 meV excitation 303 in our device is consistent with this interpre-304 tation and our DFT calculations which showed 305 that the 1.7 meV mode is related to a combined 306 vibration of the central  $C_{60}$  and the pyrene an-307 chor groups. 308

Strong electron-vibron coupling and weak vi-309 bron relaxation can further lead to avalanche 310 transport characterised by strong current fluc-311 tuations.<sup>5</sup> These fluctuations are the result of 312 occasional charge transfer events exciting the 313 molecule from its vibrational ground state and 314 setting off an avalanche of electrons tunneling 315 via vibrational excited states that have greater 316 wavefunction overlap, as shown in Figure 5a-f. 317 An avalanche is terminated when the molecule 318 returns to its ground state by tunneling induced 319 de-excitation or dissipative relaxation. Figure 320 5g shows that avalanche transport, in contrast 321 to field-induced bi-stabilities,<sup>23</sup> leads to fluctu-322 ations that persist over the entire bias range 323 corresponding to the vibrational  $0 \leftrightarrow 2$  tran-324 sition. For  $\beta eV_b < 2\hbar\omega$  ( $\beta \sim 0.5$  given by 325 the ratio of the source capacitance and the 326 total capacitance), the vibrational transitions 327  $0 \leftrightarrow 0$  and  $0 \leftrightarrow 1$  are suppressed due to FC 328 blockade (a,d). At  $2\hbar\omega \leq \beta eV_b < 3\hbar\omega$ , the 329  $0 \leftrightarrow 2$  transition enters the bias window (Figure 330 5b,e). While the transition rate is higher, the 331 system typically experiences a long wait time 332 with no current while it remains in the vibron 333 ground state. For weak vibron relaxation, oc-334 casional electron inelastic tunnelling excites the 335

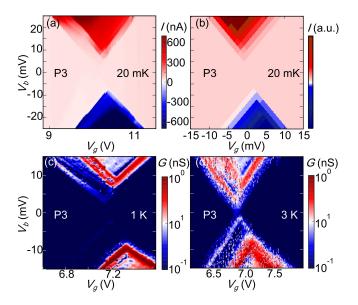


Figure 4: (a) Current stability diagram of P3 at 20 mK. (b) Simulated current stability diagram using the rate equation model with  $\lambda = 3$  and  $t_L = 0.2t_R$ , showing good qualitative agreement with (a). Conductance stability diagrams of P3 at 1 K (c) and 3 K (d). The FC gap is lifted at 3 K. Transitions due to vibron absorption are described by Bose-Einstein statistics, such that  $I_{\text{step}} \propto 1/k_BT \times 1/(exp(\hbar\omega/k_BT)-1)$ . We extract and fit the temperature dependence of Iat  $V_g = 7$  V and  $V_b = 7.2$  mV in Figure 3c and obtained a value of  $\hbar\omega = 1.7$  meV, consistent with our experimentally determined value.

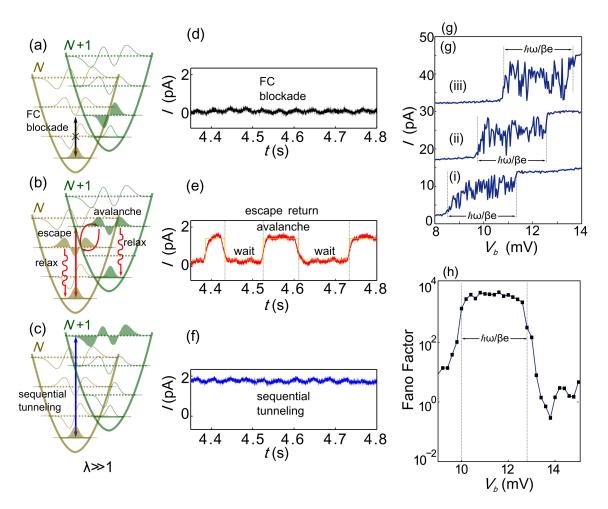


Figure 5: (a-c) Schematics for avalanche transport. (d-f) Current-time traces at  $V_b = 9$ , 12 and 14 mV. The full current-time trace over which we perform the HMM fit was measured for 20 s with a 100 kHz sampling rate. The orange curve (e) is the HMM fit to the full current-time trace. (g) IV at  $V_g =$  (i) 10.1 V, (ii) 10.15 V and (iii) 10.2 V. Curves are offset for clarity, +15 pA (ii) and +30 pA (iii). The current noise extends over an applied bias corresponding to  $\hbar\omega/\beta e$ . (h) Fano factors of the zero-frequency noise measured as a function of  $V_b$  at  $V_g = 10.15$  V indicated by the green line in Figure 3c. Giant Fano factors ~ 10<sup>3</sup> extend over an applied bias corresponding to  $\hbar\omega/\beta e$ , reflecting avalanche transport, before decreasing to ~ 1 at higher bias in accordance with sequential tunnelling.

molecule to a higher vibrational state, with sub- 385 336 sequent tunnelling events further increasing this 386 337 excitation. Having escaped the ground state, 387 338 an avalanche of tunnelling events occur. The 388 339 process terminates when the system returns to 389 340 the vibrational ground state, resulting in an- 390 341 other long wait time before the cycle repeats. 391 342 At  $\beta eV_b \geq 3\hbar\omega$ , charge transfer proceeds via 392 343 sequential tunnelling through the  $0 \leftrightarrow 3$  transi- 393 344 tion (Figure 5c, f). 394 345

To characterise the current fluctuations we 395 346 extract the  $0 \leftrightarrow 2$  escape and return rates by 396 347 fitting a current-time trace of device A mea- 397 348 sured at  $V_b = 12$  mV to a Hidden Markov 398 349 Model (HMM) assuming a two state stochas- 399 350 tic process (orange line in Figure 5e).<sup>24</sup> We 351 obtain an escape rate of 15  $\pm 2$  s<sup>-1</sup>, which 352 corresponds to a FC matrix element  $W_{0\leftrightarrow 2} \sim$ 353 0.002 and  $\lambda \sim 4$  (Supplementary section 1.9), 354 and a return rate of 22  $\pm 2$  s<sup>-1</sup>. These rates 355 place an upper-bound of  $\sim 1 \text{ s}^{-1}$  on the dis-356 sipative relaxation rate. The observation of 357 401 such a slow relaxation rate, compared to val-358 402 ues measured in time resolved spectroscopy ( $\sim$ 359  $1 \text{ ps}^{-1}$ ),<sup>25</sup> is indeed surprising. However, those 360 measurements are usually performed in a sol-361 405 vent where dissipation to solvent ions is pos-362 406 sible. Low temperature and vacuum condi-363 407 tions suppresses the dissipation rate,<sup>26</sup> which 364 408 is mostly dependent on dissipation to the elec-365 409 trodes in single-molecule junctions.<sup>10,27</sup> Fits of 366 410 the conductance peaks (Supplementary section 367 411 1.5) show that the pyrene anchors form weak  $\frac{1}{412}$ 368  $\pi$ - $\pi$  stacking interactions with the graphene 369 413 electrode (molecule-electrode coupling  $t_0 \sim 1$ 370 414 meV). While the in-plane thermal conductivity 371 415 of graphene is exceptionally large, its out-of-372 416 plane thermal conductivity is limited by weak 373 417 van der Waals interactions between adjacent 374 418 planes and substrates and can possibly suppress 375 419 vibron dissipation to the graphene electrodes.<sup>28</sup> 376 420 Vibrationally induced conformational changes 377 421 where an anharmonic potential with local mini-378 422 mas suppress dissipation is another possibility.<sup>1</sup> 379 Metastable molecular conformation can be long 380 424 lived on the order of milliseconds, consistent  $_{_{425}}$ 381 with the return rates in our system, and can be 382 426 accessed through a vibrational excited state.<sup>29</sup> 383 427 Dissipation to the electrodes is dependent on 384

the atomistic details of the vibron density of states at the molecule-electrode interface. The non-equilibrium distribution of vibrons is nontrivial and requires a self-consistent calculation of electron-vibron dynamics.

Electron avalanche transport is characterized by giant Fano factors on the order of  $10^2 \cdot 10^3$  occurring in steps over the bias window ( $\hbar \omega / \beta e$ ) corresponding to a vibron transition.<sup>5</sup> The zero frequency Fano factor  $F = S/2e\langle I \rangle$  for the excess noise  $S(0) - S(0)_{V_b=0}$  indicates the deviation from Poissonian noise, where F = 1. The noise power density  $S(\omega)$  is defined as the Fourier transform of the current-current correlation,

$$S(\omega) = \int_{-\infty}^{\infty} dt e^{i\omega t} \langle \delta I(t+t') \delta I(t') \rangle_{t'}.$$
 (1)

In Figure 5h, we determine the zero frequency Fano factors as a function of  $V_b$  (Supplementary section 1.9), taken at  $V_g = 10.15$  V indicated by the vertical green line in Figure 3c. At 10  $\leq V_b \leq 13$  mV, the Fano factors increase to an order of  $\sim 10^2 - 10^3$ , reflecting the current fluctuations due to avalanche transport. These giant Fano factors likewise persist over an applied bias corresponding to  $\hbar\omega$ . When  $V_b$  is sufficient to lift FC blockade, the Fano factor is expected to return to values of the order of 1.<sup>5</sup> At  $V_b =$ 13.4 mV, the Fano factors decrease to  $\sim 1$  in accordance with sequential transport.<sup>30</sup>

We have demonstrated a robust architecture using functionalised  $C_{60}$  bisadduct and graphene electrodes to create single-molecule transistors which enables the observation of redox-dependent FC blockade and avalanche transport. While doping-induced variations in the Fermi-level of the graphene electrodes and offset charges in the oxide can influence the alignment of the electrochemical potential of the molecule with the Fermi-level of the graphene electrodes, we show that the functionalisation of  $C_{60}$  with pyrene anchors groups can modify electron delocalization and energy levels leading to HOMO dominated transport, in contrast to previous reports of LUMO domi-

nated transport in C<sub>60</sub> transistors.<sup>10</sup> Calcula- 471 428 tions have suggested that the modification of 472 429 electron delocalization and energies via the in- 473 430 clusion of side group can be used to tune the 474 431 thermopower of single-molecule junctions.<sup>31,32</sup> 475 432 Furthermore, thermoelectric efficiency is max- 476 433 imised when charge transport across a junction 477 434 occurs through a single level with low vibra- 478 435 tional heat conductance.<sup>32</sup> Therefore, the ob- 479 436 servation of an extremely long vibron lifetime 480 437 not only offers unique potential for the funda- 481 438 mental study of quantized motion and thermal 482 439 transport on the nanoscale, but is also promis- 483 440 ing for practical applications in single-molecule 484 441 energy-conversion devices.<sup>32</sup> 485 442

## $_{443}$ Methods

#### 444 Device Fabrication and Measure-445 ments 491

The molecular devices are fabricated on a heav-446 ily doped silicon chip with a 300 nm thick oxide 492 447 which also serves as a back gate to modulate 448 charge transport through the junction. First,  $\frac{1}{494}$ 449 graphene is synthesized on liquid copper sup-  $_{_{\rm 495}}$ 450 ported on a tungsten substrate using chemi-451 cal vapour deposition.<sup>33</sup> Using a wet transfer 496 452 technique, the graphene is transferred to the 497 453 silicon substrate with pre-patterened gold elec- 498 454 trodes. The graphene electrodes are fabricated 455 based on the method of feedback-controlled 499 456 electroburning.<sup>34</sup> Fabricated nanogaps are typ-<sup>500</sup> 457 ically between 1 to 2 nm. The devices are next <sup>501</sup> 458 immersed in a 10  $\mu$ M chloroform solution con-459 taining the  $C_{60}$  bisadducts for 30 mins. We 460 wirebond the devices to our sample puck and 461 504 transfer them to our dilution fridge with a base 462 temperature of 20 mK. All electrical measure-463 ments are performed using low noise, battery 464 operated electronics, while the gate voltage was 507 465 modulated with a Keithley 2400 sourcemeter. 466 508

#### 467 DFT theoretical methods

<sup>468</sup> To calculate the vibrational modes of the <sup>511</sup> <sup>469</sup> bisadducts, we use the Harmonic approxima- <sup>512</sup> <sup>470</sup> tion method to construct the Dynamical Ma- <sup>513</sup> trix D. The xyz coordinate of the two isomers of the bisadducts were constructed and the geometry relaxation were performed with Siesta<sup>35</sup> implementation of the Density Functional Theory (DFT) by double- $\zeta$  polarized bases set (DZP) and the GGA functional with PBE parameterization to the force tolerance of 20 meV/Å. A real-space grid is defined with an equivalent energy cut-off of 250 Ry. From the relaxed xyzcoordinates of the system, a set of the xyz coordinates were generated by displacing each atom in positive and negative x, y and z directions by  $\delta q' = 0.01$  Å. The forces in three directions  $q_i = (x_i, y_i, z_i)$  on each atom were then calculated by DFT with the same parameters as the relaxed system but without geometry relaxation. These set of the force  $F_i^q = (F_i^x, F_i^y, F_i^z)$ vectors are used to construct the Dynamical matrix (Supplementary section 2.1). The electronic structure and transport calculations are performed using GOLLUM as described in.<sup>8</sup>

#### References

486

487

488

489

- (1) Galperin, M.; Ratner, M. A.; Nitzan, A. Journal of Physics: Condensed Matter 2007, 19, 103201.
- (2) Park, H.; Park, J.; Lim, A.; Anderson, E.; Alivisatos, A.; McEuen, P. <u>Nature</u> 2000, 407, 57–60.
- (3) Leturcq, R.; Stampfer, C.; Inderbitzin, K.; Durrer, L.; Hierold, C.; Mariani, E.; Schultz, M. G.; von Oppen, F.; Ensslin, K. <u>Nature Physics</u> 2009, 5, 327–331.
- (4) Burzurí, E.; Yamamoto, Y.; Warnock, M.; Zhong, X.; Park, K.; Cornia, A.; Van Der Zant, H. S. J. <u>Nano Letters</u> 2014, <u>14</u>, 3191–3196.
- (5) Koch, J.; Von Oppen, F. <u>Physical Review</u> Letters **2005**, 94.
- (6) Mol, J. A.; Lau, C. S.; Lewis, W. J. M.; Sadeghi, H.; Roche, C.; Cnossen, A.; Warner, J. H.; Lambert, C. J.; Anderson, H. L.; Briggs, G. A. D. <u>Nanoscale</u> 2015, <u>7</u>, 13181–13185.

509

510

- 514
   (7)
   Maggini, M.; Scorrano, G.; Prato, M. 554

   515
   Journal of the American Chemical Society 555

   516
   1993, 115, 9798–9799. 556
- 517
   (8) Sadeghi, H.; Mol, J. A.; Lau, C. S.;

   518
   Briggs, G. A. D.; Warner, J.; Lam- 558

   519
   bert, C. J. Proceedings of the National 559

   520
   Academy of Sciences 2015, 112, 2658- 560

   521
   2663.
- (9) Yee, S. K.; Malen, J. A.; Majumdar, A.; 562
   Segalman, R. A. <u>Nano Letters</u> 2011, <u>11</u>, 563
   4089–4094.
- (10) Schulze, G.; Franke, K. J.; Gagliardi, A.; 525 Romano, G.; Lin, C. S.; Rosa, A. L.; 565 526 Di  $^{566}$ Niehaus, T. A.; Frauenheim, T.; 527 Carlo, A.; Pecchia, A.; Pascual, J. I. 567 528 Physical Review Letters 2008,100,529 568 136801. 530 569
- 531
   (11)
   Al-Galiby, Q.; Grace, I.; Sadeghi, H.; 570

   532
   Lambert, C. J. Journal of Materials

   533
   Chemistry C
   2015, 3, 2101–2106.
- 534
   (12)
   Kubatkin, S.; Danilov, A.; Hjort, M.; 573

   535
   Cornil, J.; Brédas, J.-L.; Stuhr 

   536
   Hansen, N.; Hedegård, P.; Bjørnholm, T.

   537
   Nature 2003, 425, 698–701.
- Ke, S.-H.; Baranger, H.; Yang, W.
   Physical Review Letters 2003, 91, 116803.
- (14) Kaasbjerg, K.; Flensberg, K. <u>Nano letters</u> 579
   2008, <u>8</u>, 3809–14.
- (15) Heid, R.; Pintschovius, L.; Godard, J. M. 581
   Physical Review B 1997, 56, 5925–5936. 582
- 544
   (16)
   Lansbergen, G. P.; Rahman, R.; Ver 583

   545
   duijn, J.; Tettamanzi, G. C.; Collaert, N.; 584

   546
   Biesemans, S.; Klimeck, G.; Hollenberg, L.

   547
   C. L.; Rogge, S. Phys. Rev. Lett.
   2011, 586

   548
   107, 136602.
   587
- (17) Fuechsle, M.; Miwa, J. a.; Mahapatra, S.; 588
   Ryu, H.; Lee, S.; Warschkow, O.; Hollow
   lenberg, L. C. L.; Klimeck, G.; Simmons, M. Y. Nature Nanotechnology 591
   2012, 7, 242–246.

- (18) Bailey, S.; Visontai, D.; Lambert, C. J.; Bryce, M. R.; Frampton, H.; Chappell, D. <u>The Journal of chemical physics</u> 2014, 140, 054708.
- (19) Winkelmann, C. B.; Roch, N.; Wernsdorfer, W.; Bouchiat, V.; Balestro, F. <u>Nat</u> Phys **2009**, 5, 876–879.
- (20) Lannoo, M.; Baraff, G. A.; Schlüter, M.; Tomanek, D. <u>Physical Review B</u> **1991**, <u>44</u>, 12106–12108.
- (21) O'Brien, M. C. M. **1993**, 61, 688.

561

564

- (22) Koch, J.; Von Oppen, F.; Oreg, Y.; Sela, E. <u>Physical Review B</u> 2004, <u>70</u>, 1– 12.
- (23) Secker, D.; Wagner, S.; Ballmann, S.; Härtle, R.; Thoss, M.; Weber, H. B. <u>Physical</u> <u>Review Letters</u> **2011**, 106, 3–6.
- (24) Greenfeld, M.; Pavlichin, D. S.; Mabuchi, H.; Herschlag, D. <u>PLoS</u> <u>ONE</u> 2012, 7.
- (25) Laubereau, A.; von der Linde, D.; Kaiser, W. <u>Physical Review Letters</u> 1972, 28, 1162–1165.
- (26) Kuznetsov, A. M.; Ulstrup, J. Journal of Electroanalytical Chemistry **2004**, <u>564</u>, <u>209–222</u>.
- (27) Pascual, K. J. F.; Ignacio, J. Journal of <u>Physics: Condensed Matter</u> 2012, <u>24</u>, <u>394002</u>.
- (28) Pop, E.; Varshney, V.; a.K. Roy, A. K.
   MRS Bulletin **2012**, 37, 1273–1281.
- (29) Eggeling, C.; Fries, J. R.; Brand, L.; GÃijnther, R.; Seidel, C. A. M. Proceedings of the National Academy of Sciences **1998**, 95, 1556–1561.
- (30) Onac, E.; Balestro, F.; Trauzettel, B.; Lodewijk, C.; Kouwenhoven, L. <u>Physical</u> Review Letters **2006**, 96, 026803.
- <sup>592</sup> (31) Kim, Y.; Jeong, W.; Kim, K.; Lee, W.;
   <sup>593</sup> Reddy, P. <u>Nat Nano</u> 2014, <u>9</u>, 881–885.

 (32) Reddy, P.; Jang, S.-Y.; Segalman, R. A.;
 Majumdar, A. <u>Science</u> 2007, <u>315</u>, 1568– 1571.

597	(33)	Wu,  Y.  a.;  Fan,  Y.;  Speller,  S.;
598		Creeth, G. L.; Sadowski, J. T.;
599		He, K.; Robertson, A. W.; Allen, C. S.;
600		Warner, J. H. <u>ACS nano</u> <b>2012</b> , <u>6</u> , 5010–7.
601	(34)	Lau, C. S.; Mol, J. A.; Warner, J. H.;
601 602	(34)	Lau, C. S.; Mol, J. A.; Warner, J. H.; Briggs, G. A. D. Physical chemistry
	(34)	

(35) Sánchez-Portal, J. M. S.; Artacho, E.;
Gale, J. D.; García, A.; Junquera, J.;
Ordejón, P.; Daniel, Journal of Physics: Condensed Matter 2002, 14, 2745.

## **Acknowledgements**

We thank the Royal Society for a Newton Inter-610 national Fellowship for J. A. M. and a Univer-611 sity Research Fellowship for J. H. W., and the 612 Agency for Science Technology and Research 613 (A\*STAR) for a studentship for C. S. L. This 614 work is supported by Oxford Martin School, 615 EPSRC grants EP/J015067/1, EP/K001507/1, 616 EP/J014753/1, EP/H035818/1, EP/K030108/1 617 and the European Union Marie-Curie Net-618 work MOLESCO. This project/publication was 619 made possible through the support of a grant 620 from Templeton World Charity Foundation. 621 The opinions expressed in this publication are 622 those of the author(s) and do not necessarily 623 reflect the views of Templeton World Charity 624 Foundation. 625

## 626 Competing financial interests

<sup>627</sup> The authors declare no competing financial in-<sup>628</sup> terests.